



NEC Electronics Inc.

72C 09243 D

T-41-83

**6N137**  
**HIGH SPEED**  
**PHOTO COUPLER**  
 NEPOC SERIES

**Description**

The 6N137 is a high speed photo coupler containing a GaAsP light emitting diode and an integrated detector consisting of a photo diode and a high gain linear amplifier that drives a Schottky clamped open collector output transistor in a plastic DIP (Dual In-line Package).

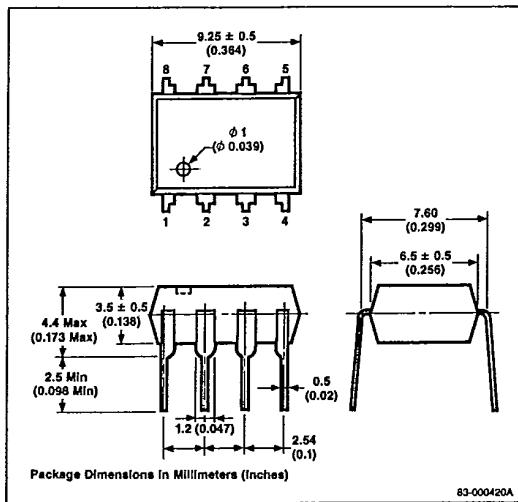
**Features**

- Ultra high speed (50ns typ)
- High isolation voltage (3000V<sub>DC</sub> min)
- Low input current requirement (5mA)
- Economical, compact, plastic dual in-line package
- TTL compatible (5V supply)

**Applications**

- Line receiver
- Floating power supply
- Computer and peripheral memory
- Replaceable with mechanical relays and reed relays
- Replaceable with pulse transformer

**Package Dimensions**



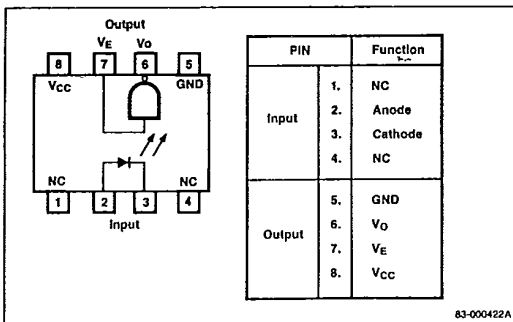
**Absolute Maximum Ratings**

T<sub>A</sub> = +25°C

<b>Diode</b>	
Reverse Voltage, V <sub>R</sub>	5V
Forward Current, I <sub>F</sub>	10mA
<b>Detector</b>	
Supply Voltage, V <sub>CC</sub>	7V
Output Voltage, V <sub>O</sub>	7V
Output Current, I <sub>O</sub>	50mA
Enable Voltage, V <sub>E</sub>	5.5V
Power Dissipation, P <sub>D</sub>	85mW
Isolation Voltage, BV <sup>1</sup>	3000V <sub>DC</sub>
Storage Temperature, T <sub>STG</sub>	-55°C to +125°C
Operating Temperature, T <sub>OP</sub>	0°C to +70°C

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**Pin Connection**





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Electrical Characteristics

T<sub>A</sub> = 0 to +75°C

Parameter	Symbol	Limits			Unit	Test Conditions
		Min	Typ	Max		
<b>Diode</b>						
Forward Voltage	V <sub>F</sub>	1.42	1.7		V	I <sub>F</sub> = 10mA, T <sub>A</sub> = 25°C
Reverse Current	I <sub>R</sub>	0.01	10		μA	V <sub>R</sub> = 5V, T <sub>A</sub> = 25°C
Capacitance	C <sub>T</sub>	60			pF	V = 0, f = 1.0MHz
<b>Detector</b>						
High Level Enable Current	I <sub>EH</sub>	-0.8			mA	V <sub>CC</sub> = 5.5V, V <sub>EH</sub> = 2.0V
Low Level Enable Current	I <sub>EL</sub>	-1.2	-2.0		mA	V <sub>CC</sub> = 5.5V, V <sub>EL</sub> = 0.5V
<b>Coupled</b>						
High Level Output Current	I <sub>OH</sub>	30	250		μA	V <sub>CC</sub> = 5.5V V <sub>O</sub> = 5.5V, I <sub>F</sub> = 250μA, V <sub>E</sub> = 2.0V
Low Level Output Voltage	V <sub>OL</sub>	0.4	0.6		V	V <sub>CC</sub> = 5.5V, V <sub>E</sub> = 2.0V, I <sub>F</sub> = 5mA, I <sub>O</sub> = 13mA
Low Level Supply Current	I <sub>CCL</sub>	10	18		mA	V <sub>CC</sub> = 5.5V, V <sub>E</sub> = 2V, I <sub>F</sub> = 10mA
High Level Supply Current	I <sub>CCH</sub>	7	15		mA	V <sub>CC</sub> = 5.5V, V <sub>E</sub> = 0.5V, I <sub>F</sub> = 0mA

Electrical Characteristics (cont)

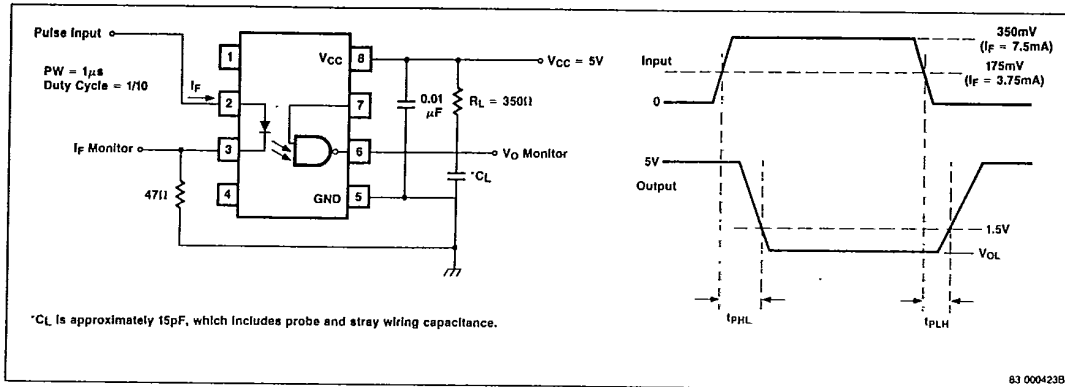
T<sub>A</sub> = +25°C

Parameter	Symbol	Limits			Unit	Test Conditions
		Min	Typ	Max		
<b>Coupled</b>						
Current Transfer Ratio	CTR	600			%	I <sub>F</sub> = 5mA, V <sub>CC</sub> = 5V R <sub>L</sub> = 100Ω
Isolation Resistance	R <sub>I-2</sub>	10 <sup>12</sup>			Ω	V <sub>IH-OUT</sub> = 1kV
Isolation Capacitance	C <sub>I-2</sub>	0.7			pF	V = 0, f = 1MHz
Propagation Delay Time to Low Output Level	t <sub>PHL</sub> <sup>2</sup>		50	75	ns	I <sub>F</sub> = 7.5mA, V <sub>CC</sub> = 5V R <sub>L</sub> = 350Ω, C <sub>L</sub> = 15pF
Propagation Delay Time to High Output Level	t <sub>PLH</sub> <sup>2</sup>		50	75	ns	
Propagation Delay Time of Enable to Low Output Level	t <sub>EHL</sub>		15		ns	I <sub>F</sub> = 7.5mA, V <sub>CC</sub> = 5V R <sub>L</sub> = 350Ω,
Propagation Delay Time of Enable to High Output Level	t <sub>ELH</sub>		30		ns	V <sub>EH</sub> = 3V C <sub>L</sub> = 15pF

Notes: 1. Measuring conditions: DC voltage for 1 min at T<sub>A</sub> = 25°C, RH = 60% between input (pins 1, 2, 3, 4 common) and output (pins 5, 6, 7, 8 common)

2. Measuring circuit

Measuring circuit

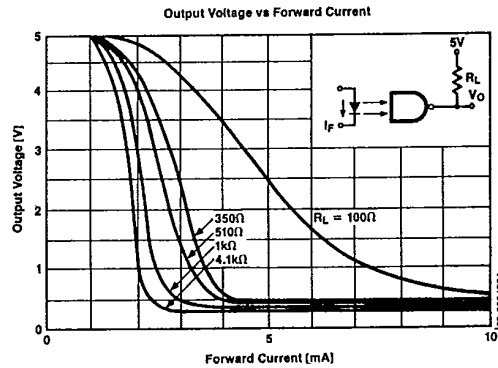
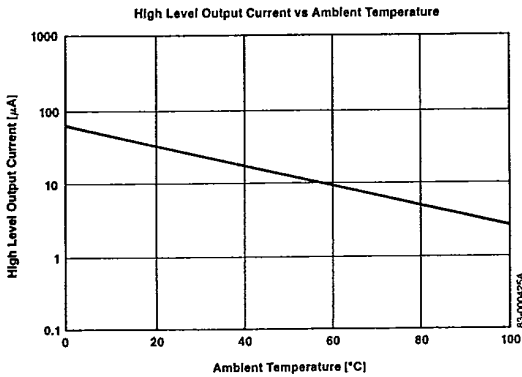
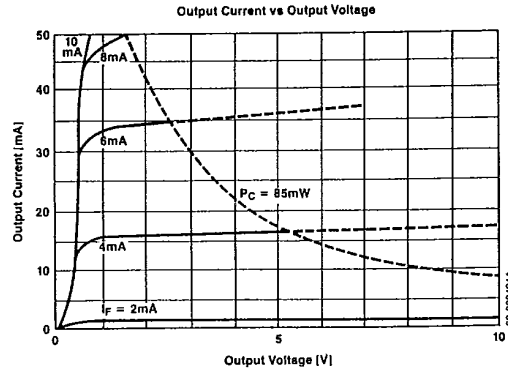
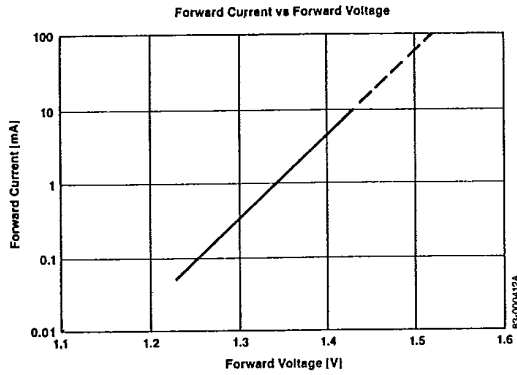




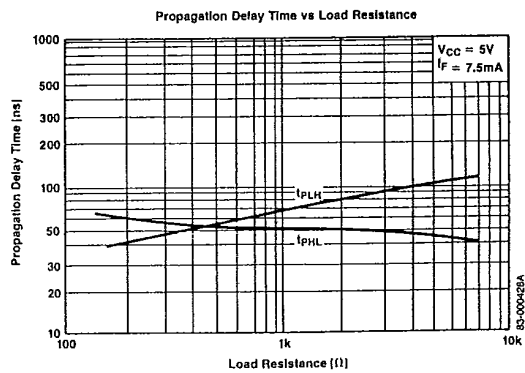
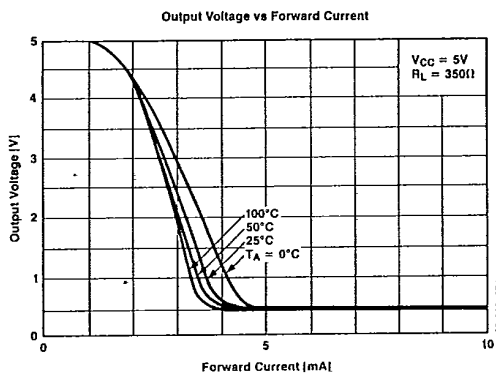
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**Typical Characteristics**

$T_A = +25^\circ\text{C}$



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Typical Characteristics (cont)

T<sub>A</sub> = +25°C

